

# Shenzhen Reflying Electronic Co., Ltd

# **TEST REPORT**

#### **SCOPE OF WORK**

SAR ASSESSMENT-AW002-PB, RPB65

#### **REPORT NUMBER**

180119021SZN-002

**ISSUE DATE** 

[REVISED DATE]

26 March 2018

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#### **PAGES**

5

#### **DOCUMENT CONTROL NUMBER**

RF Exposure © 2017 INTERTEK





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26 March 2018

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# **Test Report**

Applicant: Shenzhen Reflying Electronic Co., Ltd Number: 180119021SZN-002

6 Bldg, GaoXinJian Industrial zone, HePing village, Date:

Fuyong Town, Bao'an district, Shenzhen,

Guangdong, China.

Sample Description

Product : Dual Charge Power Bank Model No. : AW002-PB,RPB65

Brand Name : NA

Electrical Rating : Input: DC 5V, 2.1A; Output: DC 5V, 1A

Date Received : 19 January 2018

Date Test Conducted : 26 March 2018

Test Requested : Test for compliance with CFR 47 part 1

Test Method : Environmental evaluation and exposure limit according to FCC

CFR 47 part 1, 1.1307(c) and (d), 1.1310

Test Result : Pass

Conclusion : When determining of test conclusion, measurement uncertainty of tests have

been considered.

End of Page

Prepared and Checked By: Approved By:

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Engineer
Technical

Engineer Technical Supervisor
Date: 26 March 2018

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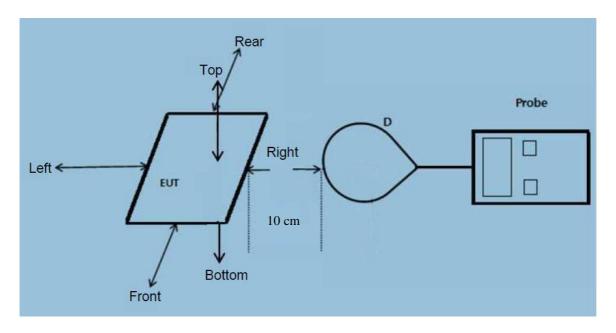
#### Intertek Testing Service Shenzhen Ltd. Longhua Branch

1F/2F, Building B, QiaoAn Scientific Technology Park, Shangkeng Community, Guanhu Subdistrict, Longhua District, Shenzhen, P.R. China. Tel: (86 755) 8601 6288 Fax: (86 755) 8601 6751



# **Test Report**

## **Test Setup Configuration**



#### Note

- The RF exposure test is performed in the shield room.
- The test distance is between the edge of the charger and the geometric centre of probe.
- The Model: RPB65 is the same as the Model: AW002-PB in hardware and electronic aspect. The difference in model number and appearance serve as marketing strategy.

#### **Test Equipment List**

Name of instrument	Model	Manufacturer	Cal. Date	Due Date
Exposure Level Tester	ELT-4002304/03	Narda	21-Mar-18	21-Mar-19
Field Probe	HI-6105	ETS	21-Mar-18	21-Mar-19
Laser Data Interface	HI-6113	ETS	21-Mar-18	21-Mar-19



#### **Reference Limit:**

# Environmental evaluation and exposure limit according to FCC CFR 47 part 1, 1.1307(c) and (d), 1.1310

According to FCC 1.1310: The criteria listed in the following table shall be used to evaluate the environment impact of human exposure to radio frequency (RF) radiation.

#### LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)

Frequency Range (MHz)	Electric field strength (V/m)	Magnetic Field Strength (A/m)	Power Density (mW/cm²)	Average Time (minutes)			
(A) Limits for Occupational/Controlled Exposure							
0.3 – 3.0	614	1.63	(100)*	6			
(B) Limits for General Population/Uncontrolled Exposure							
0.3 – 1.34	614	1.63	(100)* 30				

Note: \* = Plane wave equivalent power density

**Test Mode:** Charging and power transfer

#### **Test Result:**

H-Field Strength at 10 cm from the edges surrounding the EUT

Frequency Range (MHz)	EUT Operation mode	Probe Position Front (A/m)	Probe Position Rear (A/m)	Probe Position Left (A/m)	Probe Position Right (A/m)	Probe Position Top (A/m)	Limits (A/m)
0.550	1% charged	0.037	0.035	0.023	0.043	0.040	1.63
0.550	50% charged	0.036	0.033	0.024	0.041	0.038	1.63
0.550	99% charged	0.033	0.034	0.023	0.042	0.036	1.63
0.550	Stand-by	0.032	0.035	0.022	0.038	0.035	1.63

E-Field Strength at 10 cm from the edges surrounding the EUT

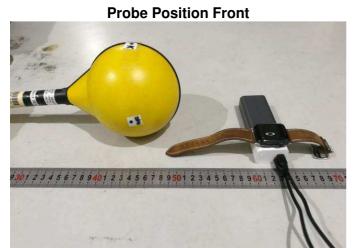
Frequency Range (MHz)	EUT Operation mode	Probe Position Front (V/m)	Probe Position Rear (V/m)	Probe Position Left (V/m)	Probe Position Right (V/m)	Probe Position Top (V/m)	Limits (V/m)
0.550	1% charged	0.431	0.382	0.324	0.490	0.463	614
0.550	50% charged	0.404	0.412	0.318	0.467	0.433	614
0.550	99% charged	0.394	0.381	0.318	0.455	0.429	614
0.550	Stand-by	0.349	0.321	0.375	0.426	0.410	614

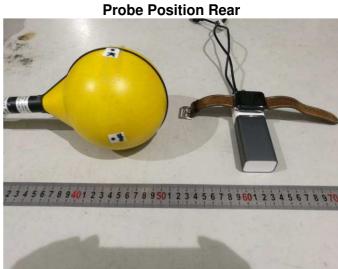


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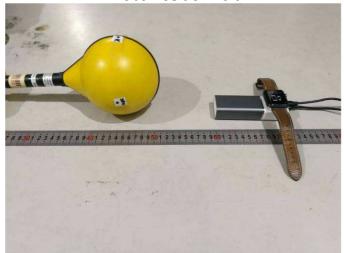
## Configuration photo of the test:

### H-Field Strength

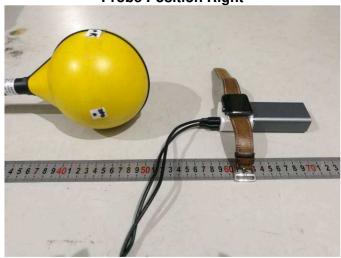




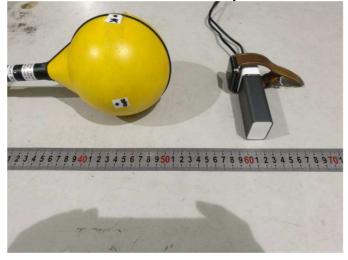
**Probe Position Left** 



**Probe Position Right** 



**Probe Position Top** 

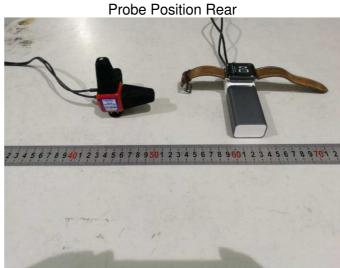




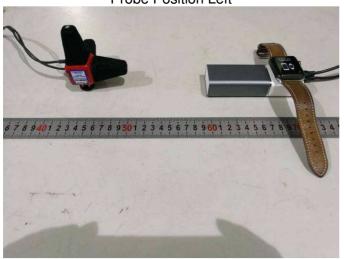
**TEST REPORT** 

# E-Field Strength

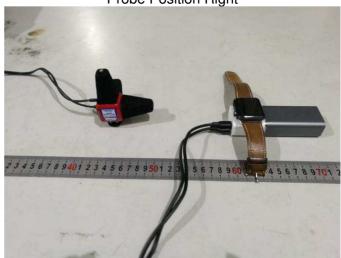




Probe Position Left







**Probe Position Top** 

